
Update on the design of SMD SiPM and dimpled tile

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Dec. 9, 2013

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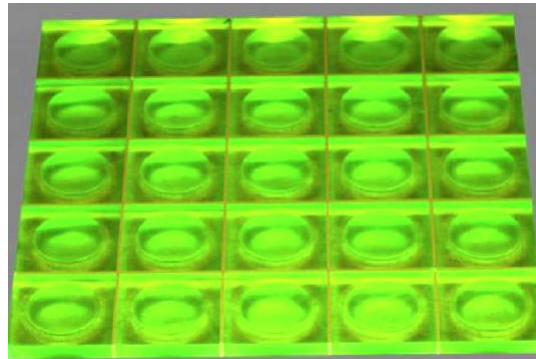


Outline

- Review
 - Uniformity scan at MPI, Munich (Aug, 2013)
- Simulation
 - SMD design: (center) bottom surface coupling
 - Present design: side surface coupling
- Summary and Plan

SMD SiPM

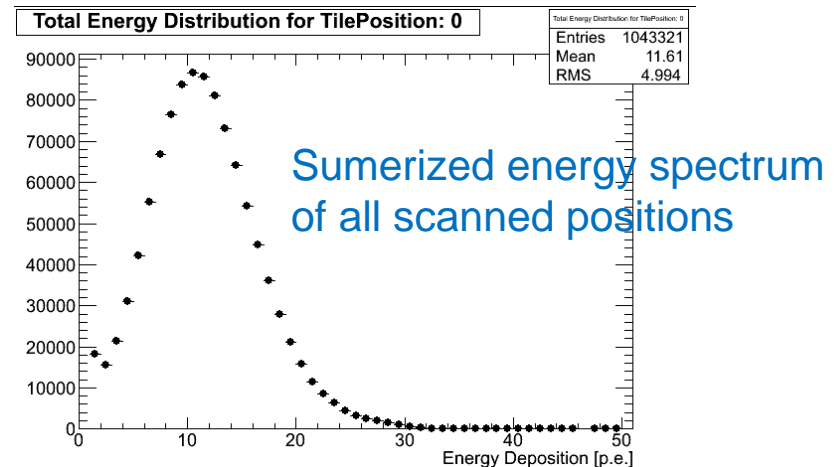
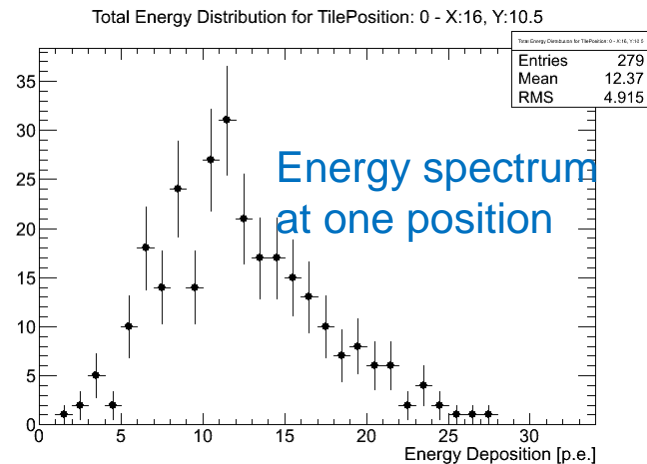
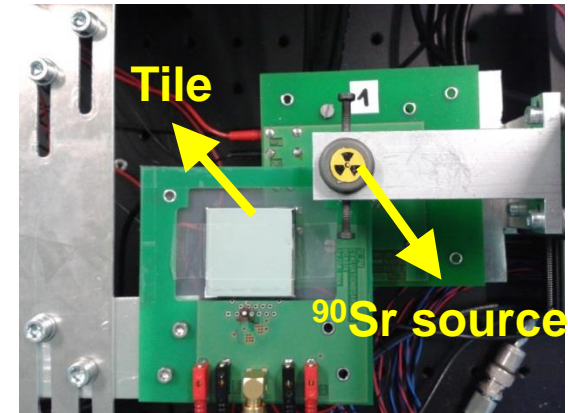
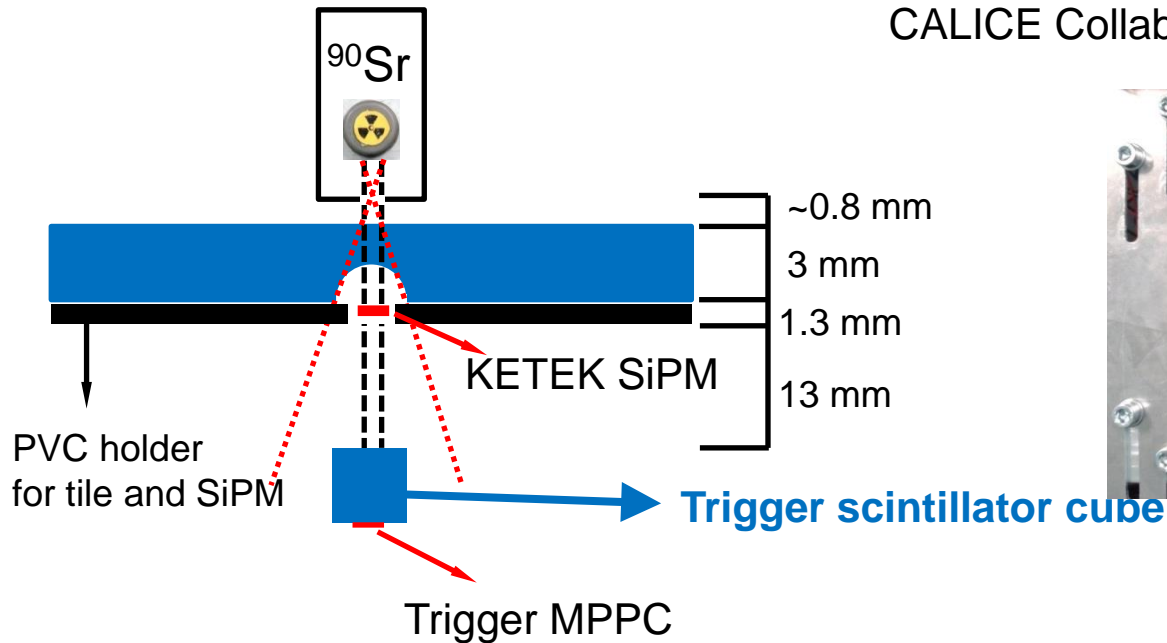
- Motivations
 - No pins: more tolerance for alignment
 - Easier to solder on HBU boards automatically
 - Massive assembly machine (Phi Chau's talk)
- Mega-tiles initiated by NIU
 - Large concave dimple in the bottom of tile



Ref: Nuclear Instruments and Methods in Physics Research A 605 (2009) 277

Review: teststand in MPI Munich

CALICE Collab. Meeting, Annecy, Sep 2013

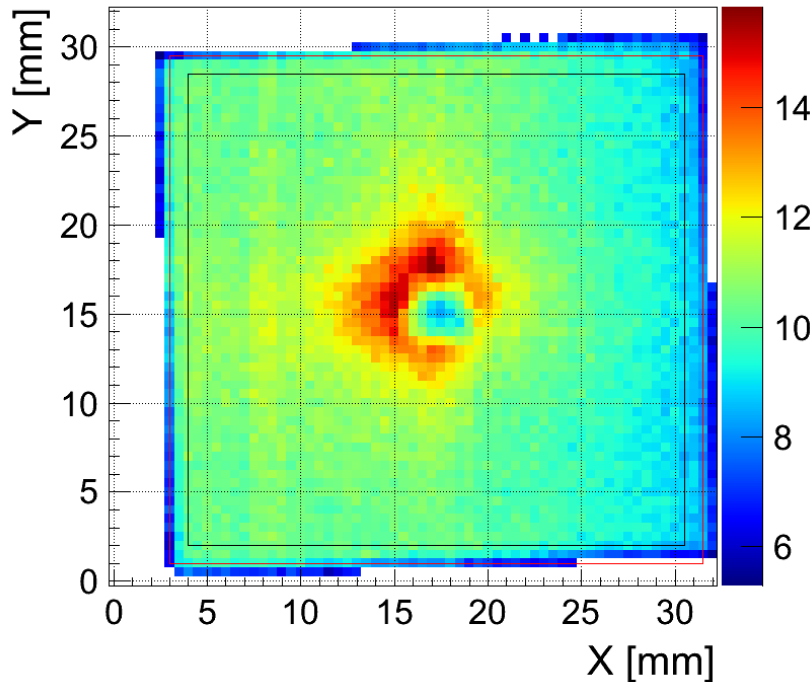


Review: uniformity of center-dimpled tile



CALICE Collab. Meeting, Annecy, Sep 2013

Dome height: 0.5mm; box depth: 1.5 mm

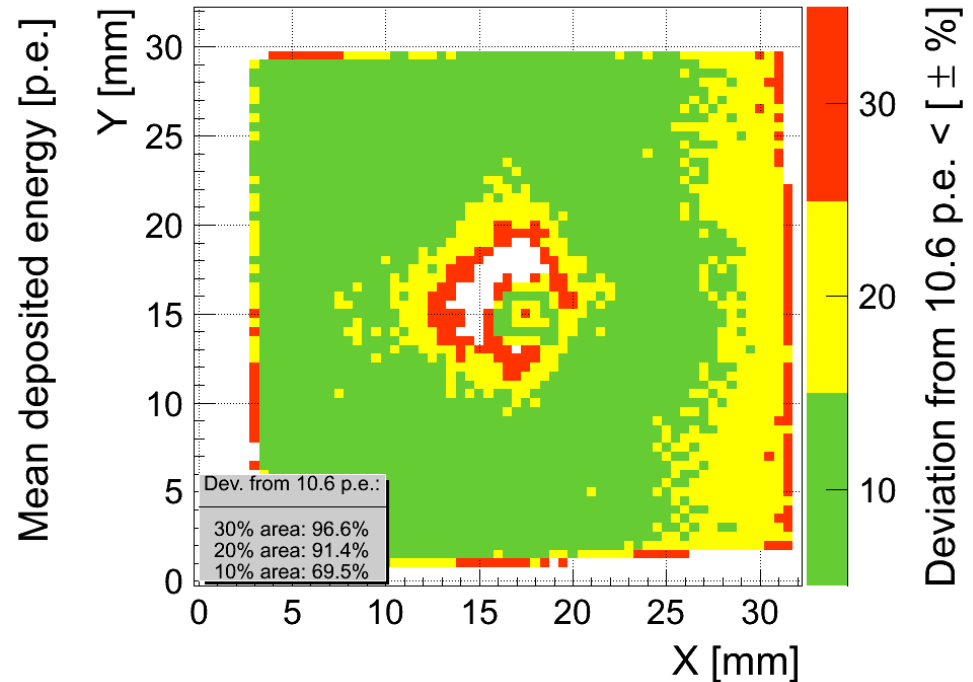


Mean 10.6 p.e. detected



Higher response?

Larger SiPM sensitive area: e.g. 2x2mm



96.6% area: 30% dev.

91.4% area: 20% dev.

69.5% area: 10% dev.



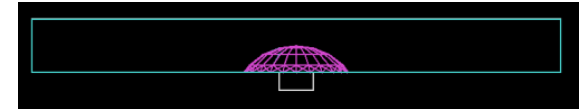
Better uniformity?

Wider and shallower dimple

Simulation: SMD SiPM + dimpled tile

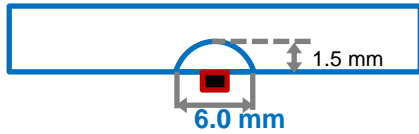
- Geometry
 - Dimpled tile: $30 \times 30 \times 3 \text{ mm}$
 - SiPMs (used same PDE curve)
 - KETEK PM11*: $1.2 \times 1.2 \text{ mm}$
 - KETEK PM22*: $2.0 \times 2.0 \text{ mm}$
 - Reflective foil:
 - 3M ESR: curve of reflectivity vs wavelength
- Primary particle generator
 - Fixed energy: 2.28 MeV (Max. in Sr-90 Beta spectrum)
- Simulation scan
 - 30x30bins; 100 events/bin

SiPM flush with bottom surface

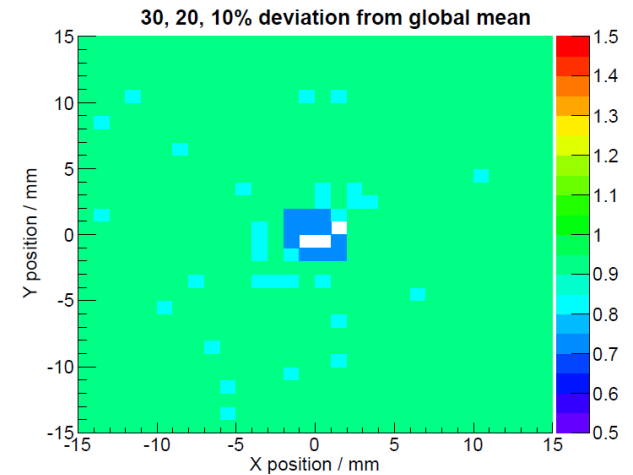
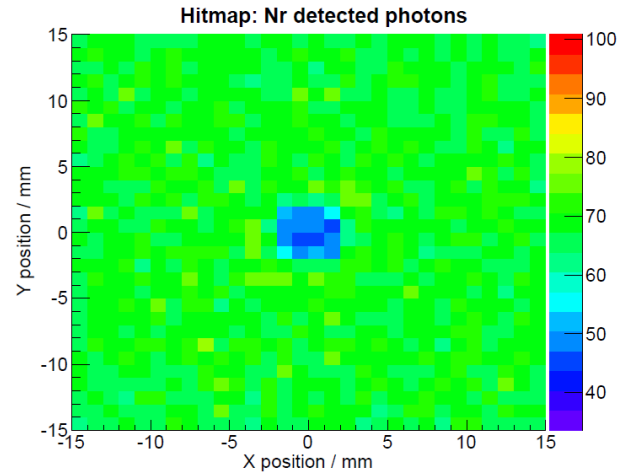


1.2×1.2 mm SiPM

Mean 67 p.e.

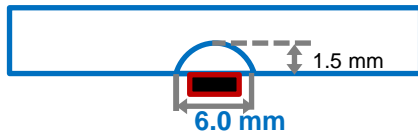


99.7% area: 30% dev.
98.4% area: 20% dev.
95.0% area: 10% dev.

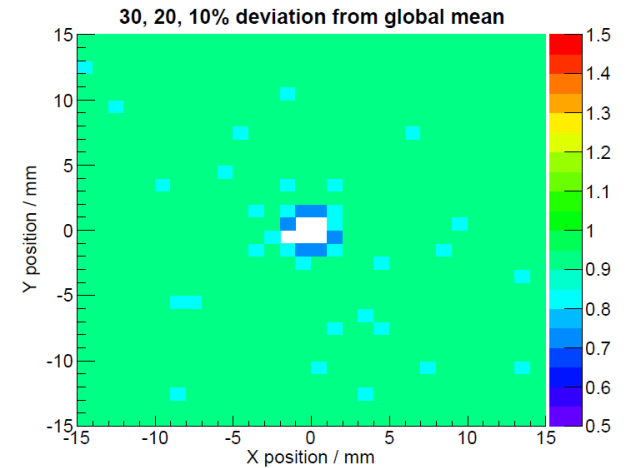
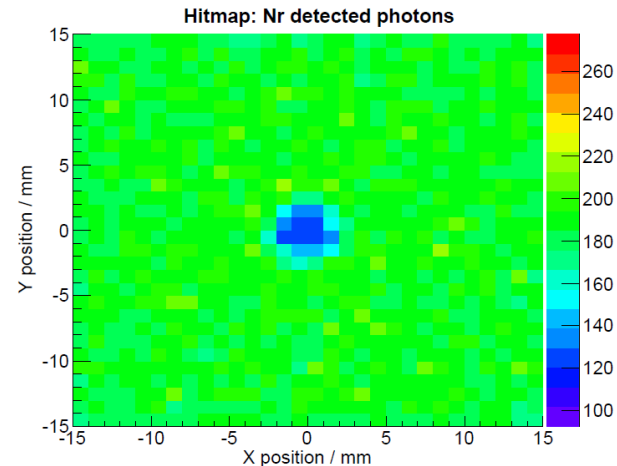


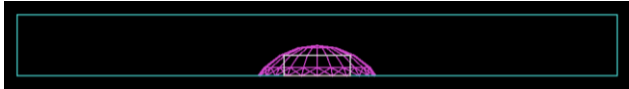
2.0×2.0 mm SiPM

Mean 185 p.e.



99.4% area: 30% dev.
99.0% area: 20% dev.
95.2% area: 10% dev.

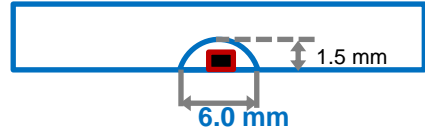




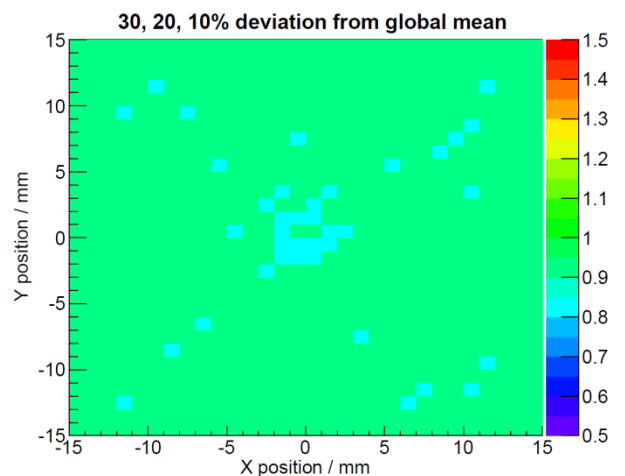
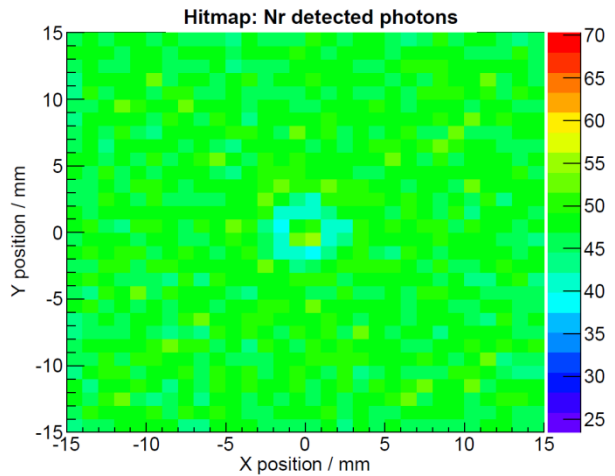
SiPM: 1.0mm inside dimple

1.2 × 1.2 mm SiPM

Mean 47 p.e. ↓

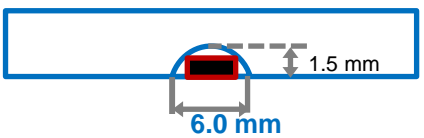


- 100% area: 30% dev. ↑
- 100% area: 20% dev. ↑
- 95.8% area: 10% dev. ↑

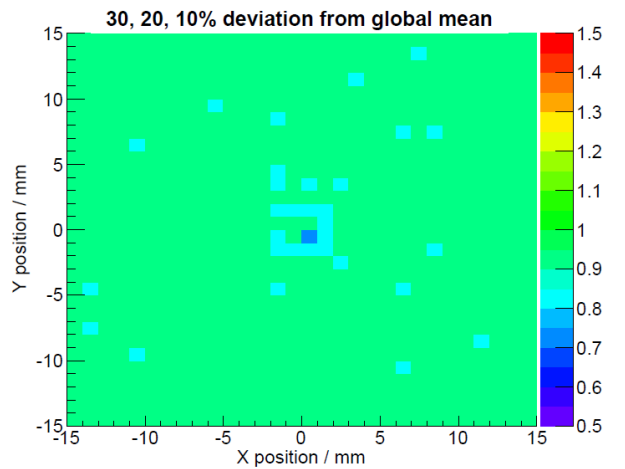
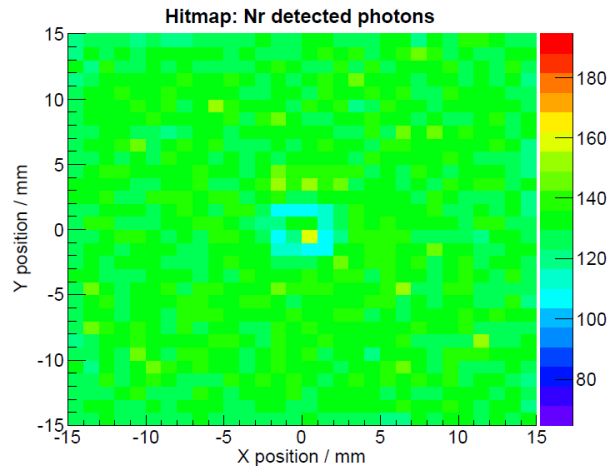


2.0 × 2.0 mm SiPM

Mean 130 p.e. ↓

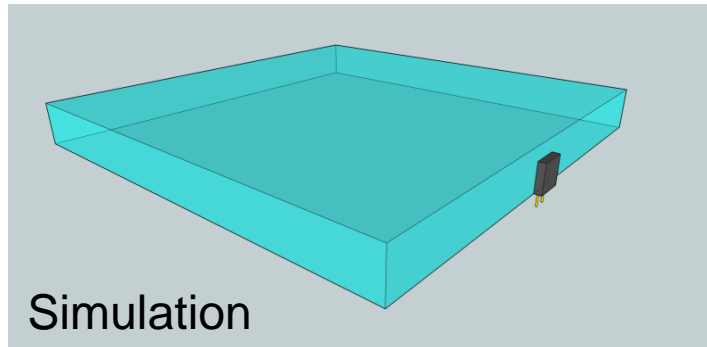


- 100% area: 30% dev. ↑
- 99.9% area: 20% dev. ↑
- 96.4% area: 10% dev. ↑

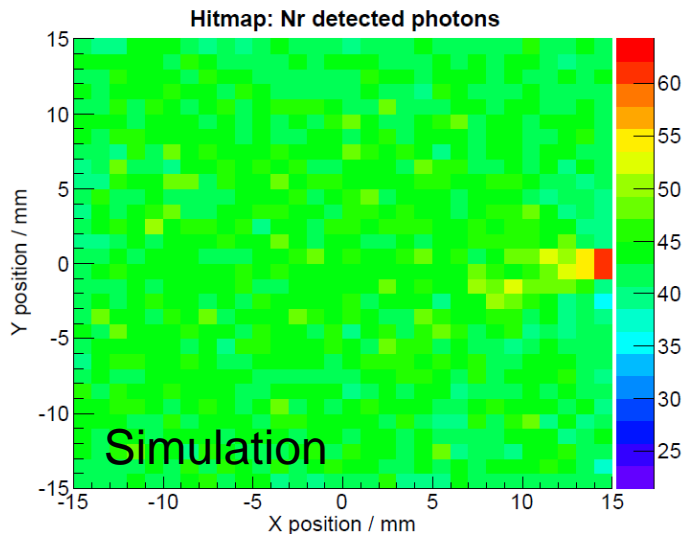


Side surface coupling: MC vs measurement

Tile: $30 \times 30 \times 3$ mm; **no dimple**



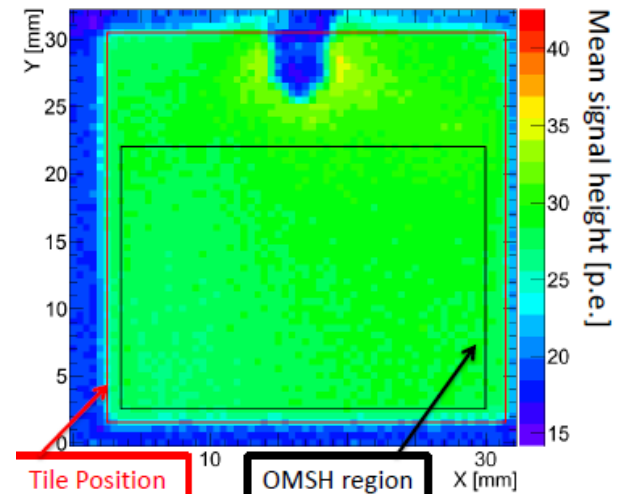
KETEK SiPM 1.2×1.2 mm: mean 42 p.e.
mean **29.2 p.e./mm²** can be foreseen



Uniformity measurement of DESY tile at MPI



MPPC 1×1 mm:
Mean 28.4 p.e.



Ref: Christian Soldner, CALICE Collab. Meeting,
Shinshu Japan, Mar. 2012

Summary

- Present design (side-surface coupling)
 - Simulation can be compared with measurement
- Simulation for SMD design
 - More p.e.s by larger SiPM sensitive area (roughly proportional)
 - SMD SiPM (sensitive surface)
 - Flush: more p.e. but less uniformity
 - 1mm inside dimple: better uniformity; less p.e.

Plan

- Updated SMD design
 - Uniformity measurement
 - Compare with simulation
- SMD design for HBU boards
 - Collaboration-wide efforts

Thank you!

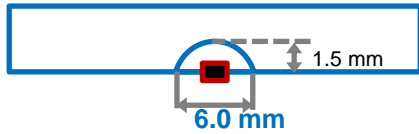


SiPM 0.5mm inside dimple

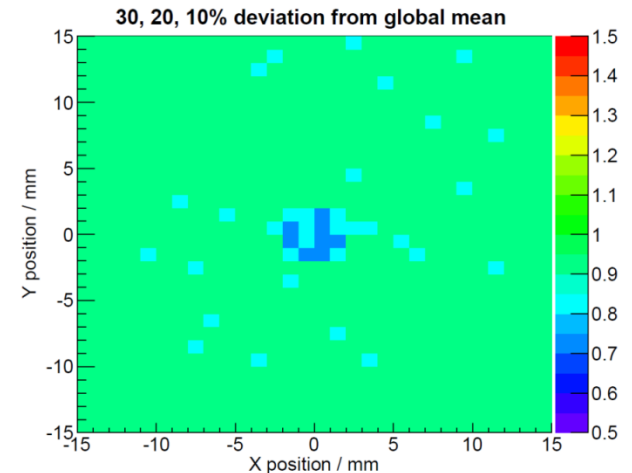
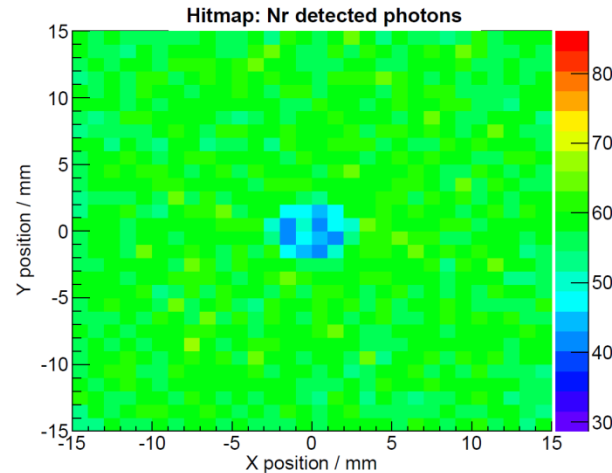


1.2×1.2 mm SiPM

Mean 57 p.e.

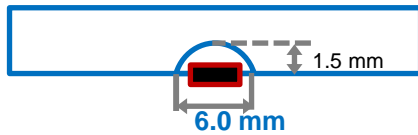


100% area: 30% dev.
99.1% area: 20% dev.
95.4% area: 10% dev.

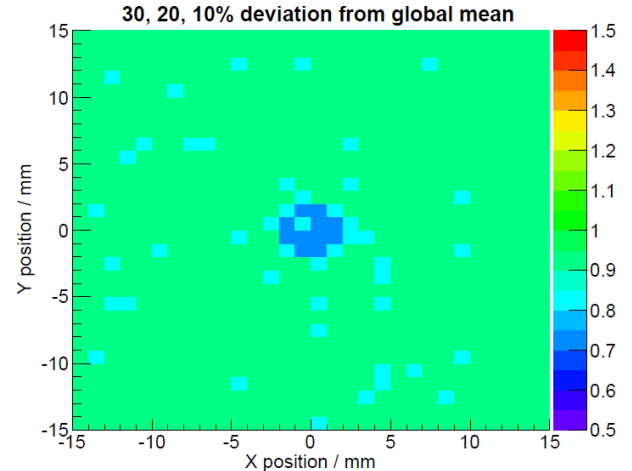
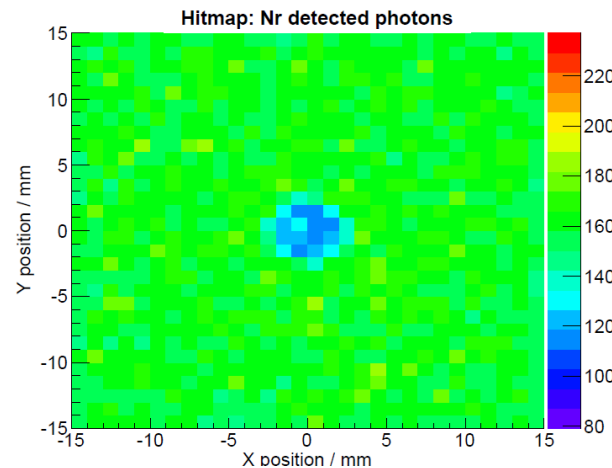


2.0×2.0 mm SiPM

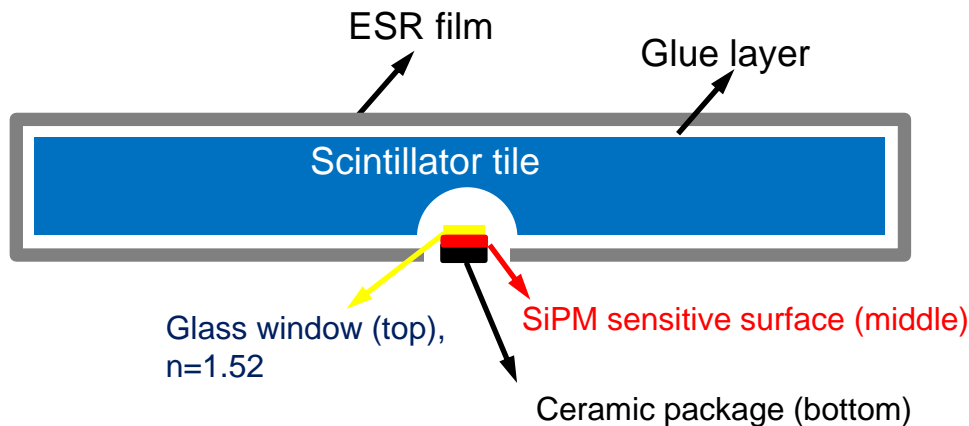
Mean 158 p.e.



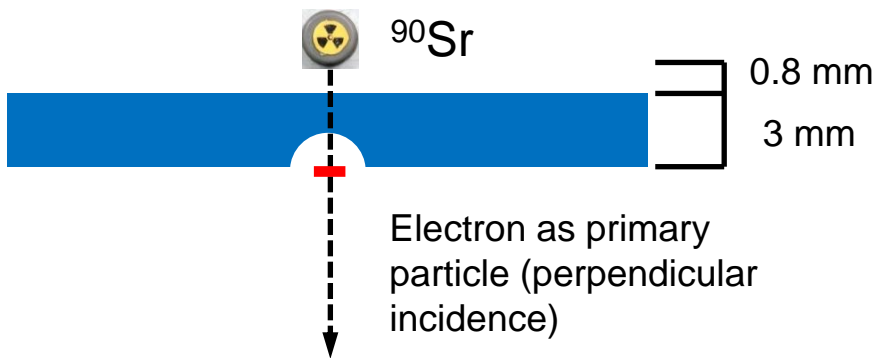
100% area: 30% dev.
98.8% area: 20% dev.
93.6% area: 10% dev.



Simulation: setup for uniformity scan

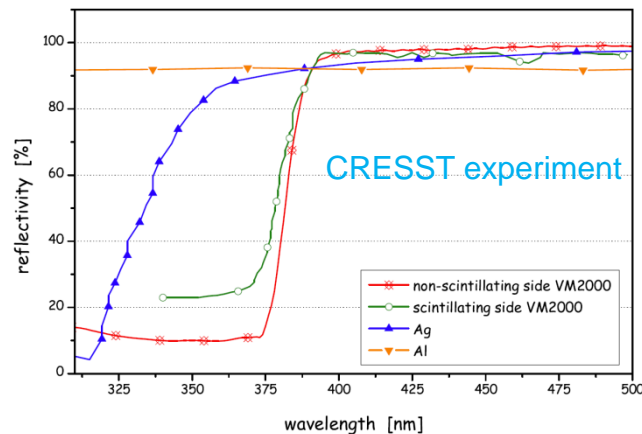


Scintillator tile: 30x30x3 mm³
 KETEK SiPM: 1.2x1.2 mm²
 Geant4 9.6.0.p01
 Optical boundary model:
 polished or ground (UNIFIED Model)



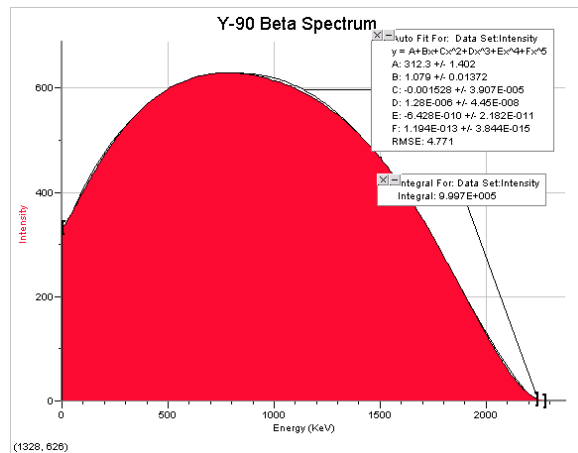
Scan step size: 1 mm
 1 run: simulate 50 events at each position
 30x30 positions to cover the whole tile area

Measured curve:
ESR reflectivity vs wavelength

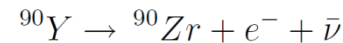
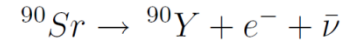


Plot courtesy of
Frank Simon

Simulation: details

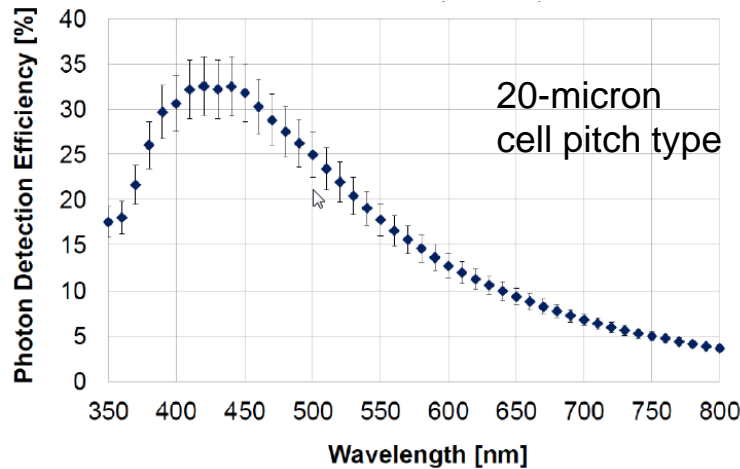


^{90}Sr energy spectrum:
 use normalized polynomial fitting as p.d.f. to sample



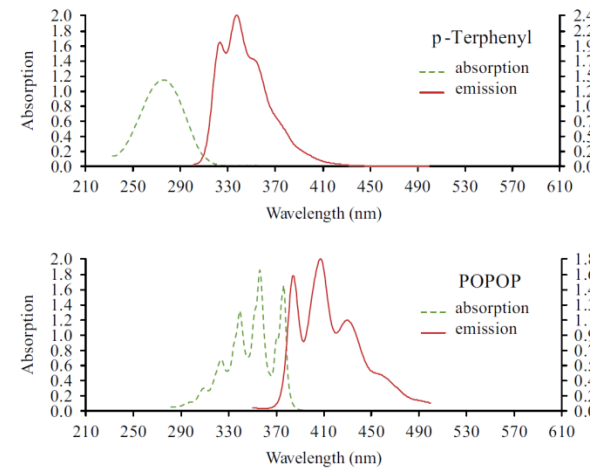
Ref 1: Silicon Strips and Pixel Technologies, Excellence in Detectors and Instrumentation Technologies 2011, CERN

KETEK PDE curve



Ref 2: SiPM Development at KETEK, CALICE Collaboration Meeting, March 2013 Hamburg

Scintillator emission spectra



Scintillator from NA62, produced by IHEP (Protvino, Russia)

Ref 3: Nuclear Instruments and Methods in Physics Research A 577 (2007) 523